# mail

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#### **IPAD™**

### EMI FILTER AND LINE TERMINATION FOR USB UPSTREAM PORTS

#### **APPLICATIONS**

EMI Filter and line termination for USB upstream ports on:

- USB Hubs
- PC peripherals

#### FEATURES

- Monolithic device with recommended line termination for USB upstream ports
- Integrated Rt series termination and Ct bypassing capacitors.
- Integrated ESD protection
- Small package size

#### DESCRIPTION

The USB specification requires upstream ports to be terminated with pull-up resistors from the D+ and D- lines to Vbus. On the implementation of USB systems, the radiated and conducted EMI should be kept within the required levels as stated by the FCC regulations. In addition to the requirements of termination and EMC compatibility, the computing devices are required to be tested for ESD susceptibility.

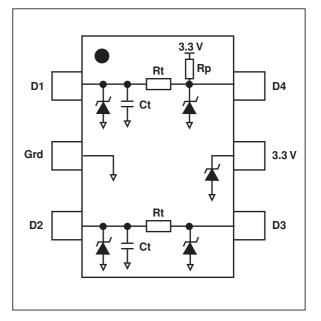
The USBUF01P6 provides the recommended line termination while implementing a low pass filter to limit EMI levels and providing ESD protection which exceeds IEC61000-4-2 level 4 standard. The device is packaged in a SOT-666 which is the smallest available lead frame package (45% smaller than the standard SOT323).

#### **BENEFITS**

- EMI / RFI noise suppression
- Required line termination for USB upstream ports
- ESD protection exceeding IEC61000-4-2 level 4
- High flexibility in the design of high density boards
- Tailored to meet USB 2.0 standard (low speed and high speed data transmission)

**SOT-666** 

#### **FUNCTIONAL DIAGRAM**



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### COMPLIES WITH THE FOLLOWING ESD STANDARDS:

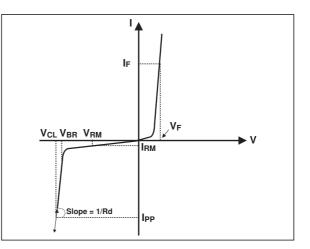
 $\begin{array}{l} \text{IEC61000-4-2, level 4} \\ \pm 15 \text{ kV (air discharge)} \\ \pm 8 \text{ kV (contact discharge)} \\ \text{MIL STD 883E, Method 3015-7} \\ \text{Class 3 } C = 100 \text{ pF } R = 1500 \ \Omega \\ \text{3 positive strikes and 3 negative strikes (F = 1 \text{ Hz})} \end{array}$ 

#### ABSOLUTE RATINGS (Tamb = 25°C)

Symbol	Parameter	Value	Unit
V <sub>PP</sub>	ESD discharge IEC 61000-4-2, air discharge ESD discharge IEC 61000-4-2, contact discharge ESD discharge - MIL STD 883E - Method 3015-7	±16 ±9 ±25	kV kV kV
Tj	Maximum junction temperature	150	°C
T <sub>stg</sub>	Storage temperature range	- 55 to +150	°C
TL	Lead solder temperature (10 second duration)	260	°C
T <sub>op</sub>	Operating temperature range	- 40 to + 85	°C

#### ELECTRICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C)

Symbol	Parameter		
$V_{BR}$	Breakdown voltage		
I <sub>RM</sub>	Leakage current @ V <sub>RM</sub>		
V <sub>RM</sub>	Stand-off voltage		
V <sub>CL</sub>	Clamping voltage		
Rd	Dynamic impedance		
IPP	Peak pulse current		
αΤ	Voltage temperature coefficient		
VF	Forward voltage drop		

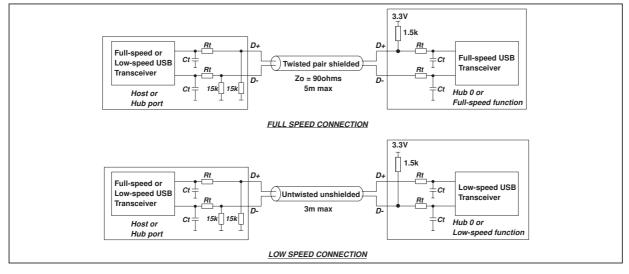


Symbol	Test conditions		Тур.	Max.	Unit
$V_{BR}$	I <sub>R</sub> = 1 mA	6		10	V
I <sub>RM</sub>	V <sub>RM</sub> = 3.3V per line			500	nA
Rt	Tolerance ± 10%		33		Ω
Rp	Tolerance ± 10%		1.5		kΩ
Ct	Tolerance ± 20%		47		pF

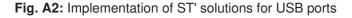
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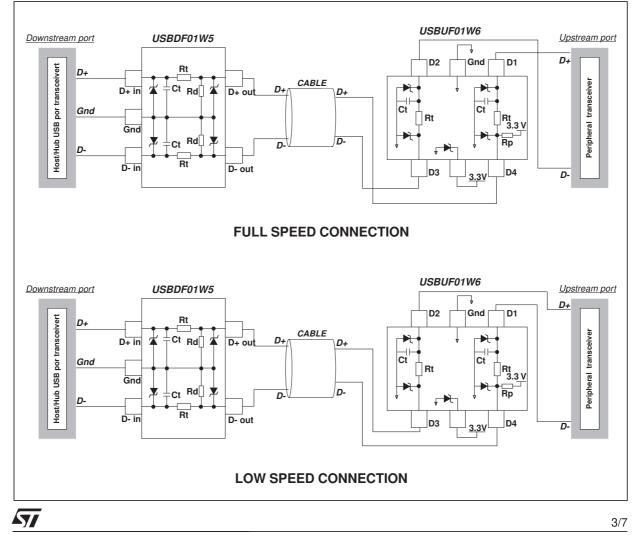
#### **TECHNICAL INFORMATION**

Fig. A1: USB Standard requirements



#### **APPLICATION EXAMPLE**





#### **EMI FILTERING**

Current FCC regulations requires that class B computing devices meet specified maximum levels for both radiated and conducted EMI.

- Radiated EMI covers the frequency range from 30MHz to 1GHz.
- Conducted EMI covers the 450kHz to 30MHz range.

For the types of devices utilizing the USB, the most difficult test to pass is usually the radiated EMI test. For this reason the USBUF01P6 device is aiming to minimize radiated EMI. The differential signal (D+ and D-) of the USB does not contribute significantly to radiated or conducted

EMI because the magnetic field of both conductors cancels each other.

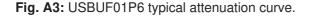
The inside of the PC environment is very noisy and designers must minimize noise coupling from the different sources. D+ and D- must not be routed near high speed lines (clocks spikes).

Induced common mode noise can be minimized by running pairs of USB signals parallel to each other and running grounded guard trace on each side of the signal pair from the USB controller to the USBUF device. If possible, locate the USBUF device physically near the USB connectors. Distance between the USB controller and the USB connector must be minimized.

The 47pF (Ct) capacitors are used to bypass high frequency energy to ground and for edge control, and are placed between the driver chip and the series termination resistors (Rt). Both Ct and Rt should be placed as close to the driver chip as is practicable.

The USBUF01P6 ensures a filtering protection against ElectroMagnetic and RadioFrequency Interferences thanks to its low-pass filter structure. This filter is characterized by the following parameters :

- cut-off frequency
- Insertion loss
- high frequency rejection.



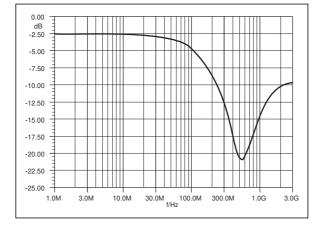
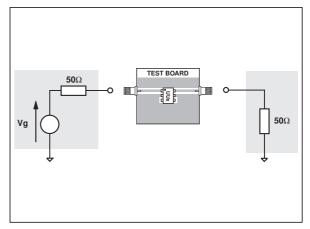


Fig. A4: Measurement configuration



#### **ESD PROTECTION**

In addition to the requirements of termination and EMC compatibility, computing devices are required to be tested for ESD susceptibility. This test is described in the IEC 61000-4-2 and is already in place in Europe. This test requires that a device tolerates ESD events and remains operational without user intervention.

The USBUF01P6 is particularly optimized to perform ESD protection. ESD protection is based on the use of device which clamps at:

$$V_{cl} = V_{BR} + R_d.I_{PP}$$

This protection function is splitted in 2 stages. As shown in figure A5, the ESD strikes are clamped by the first stage S1 and then its remaining overvoltage is applied to the second stage through the resistor Rt. Such a configuration makes the output voltage very low at the output.

Fig. A5: USBUF01P6 ESD clamping behavior

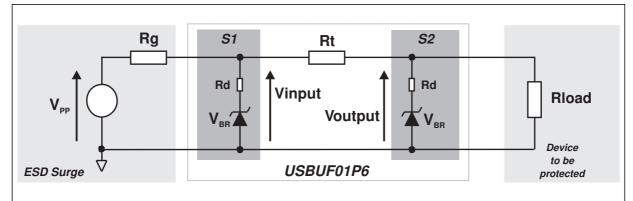
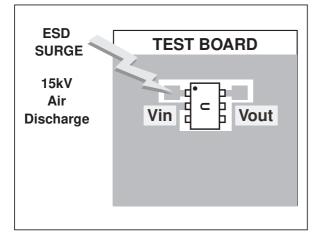


Fig. A6: Measurement board



To have a good approximation of the remaining voltages at both Vin and Vout stages, we give the typical dynamical resistance value Rd. By taking into account these following hypothesis : Rt>Rd, Rg>Rd and Rload>Rd, it gives these formulas:

$$Vinput = \frac{R_{g}.V_{BR} + R_{d}.V_{g}}{R_{g}}$$
$$Voutput = \frac{R_{t}.V_{BR} + R_{d}.Vinput}{R_{t}}$$

The results of the calculation done for Vg=8kV, Rg=330 $\Omega$  (IEC61000-4-2 standard), V<sub>BR</sub>=7V (typ.) and Rd = 2 $\Omega$  (typ.) give:

Voutput = 10.36 V

This confirms the very low remaining voltage across the device to be protected. It is also important to note that in this approximation the parasitic inductance effect was not taken into account. This could be few tenths of volts during few ns at the Vinput side. This parasitic effect is not present at the Voutput side due the low current involved after the resistance Rt.

The measurements done hereafter show very clearly (Fig. A7) the high efficiency of the ESD protection :

- no influence of the parasitic inductances on Voutput stage

- Voutput clamping voltage very close to  $V_{BR}$  (breakdown voltage) in the positive way and -V\_F (forward voltage) in the negative way



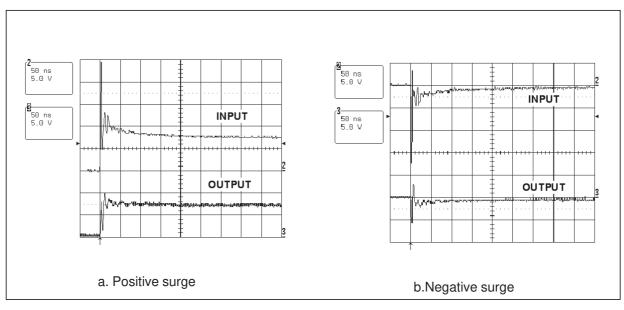
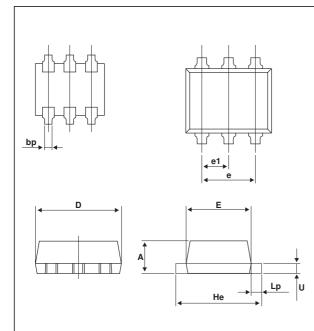


Fig. A7: Remaining voltage at both stages S1 (Vinput) and S2 (Voutput) during ESD surge.

Please note that the USBUF01P6 is not only acting for positive ESD surges but also for negative ones. For these kinds of disturbances it clamps close to ground voltage as shown in Fig. A7b.

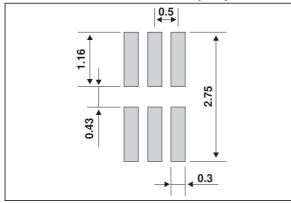
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#### PACKAGE MECHANICAL DATA. SOT-666



REF.	DIMENSIONS				
	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
А	0.50	0.60	0.020	0.024	
bp	0.17	0.27	0.007	0.011	
С	0.08	0.18	0.003	0.007	
D	1.50	1.70	0.060	0.067	
Е	1.10	1.30	0.043	0.051	
е	1.00		0.040		
e1	0.50		0.020		
He	1.50	1.70	0.059	0.067	

#### **RECOMMENDED FOOTPRINT (mm)**



#### **MECHANICAL SPECIFICATIONS**

Lead plating	Tin-lead
Lead plating thickness	5μm min 25μm max
Lead material	Sn / Pb (70% to 90%Sn)
Lead coplanarity	10µm max
Body material	Molded epoxy
Flammability	UL94V-0

#### MARKING

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
USBUF01P6	U	SOT-666	2.9 mg	3000	Tape & reel

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